MBRM2H100T3G, NRVBM2H100T3G

Surface Mount Schottky Power Rectifier

POWERMITE® Power Surface Mount Package

The Schottky Powermite[®] employs the Schottky Barrier principle with a barrier metal and epitaxial construction that produces optimal forward voltage drop-reverse current tradeoff. The advanced packaging techniques provide for a highly efficient micro miniature, space saving surface mount Rectifier. With its unique heatsink design, the Powermite[®] has the same thermal performance as the SMA while being 50% smaller in footprint area. Because of its small size, it is ideal for use in portable and battery powered products such as cellular and cordless phones, chargers, notebook computers, printers, PDAs and PCMCIA cards. Typical applications are AC–DC and DC–DC converters, reverse battery protection, and "ORing" of multiple supply voltages and any other application where performance and size are critical.

Features

- Low Profile Maximum Height of 1.1 mm
- Small Footprint Footprint Area of 8.45 mm²
- Low V_F Provides Higher Efficiency and Extends Battery Life
- Supplied in 12 mm Tape and Reel
- Low Thermal Resistance with Direct Thermal Path of Die on Exposed Cathode Heat Sink
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- This is a Pb-Free Device

Mechanical Characteristics:

- Powermite[®] is JEDEC Registered as D0-216AA
- Case: Molded Epoxy
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 16.3 mg (Approximately)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Maximum for 10 Seconds

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ON Semiconductor®

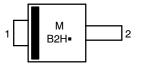
http://onsemi.com

SCHOTTKY BARRIER RECTIFIER 2.0 AMPERES, 100 VOLTS



POWERMITE CASE 457

MARKING DIAGRAM



M = Date Code B2H = Device Code ■ = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping [†]
MBRM2H100T3G	Powermite (Pb-Free)	12000/Tape & Reel
NRVBM2H100T3G	Powermite (Pb-Free)	12000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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MAXIMUM RATINGS

Rating	S	ymbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	100	V
Average Rectified Forward Current $(T_L = 160^{\circ}C)$		I _O	2.0	Α
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)		I _{FSM}	50	Α
Storage and Operating Junction Temperature Range (Note 1)	Т	stg, TJ	-65 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Lead (Note 2)	Ψ_{JCL}	12	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	75	°C/W
Thermal Resistance, Junction-to-Ambient (Note 3)	$R_{\theta JA}$	260	°C/W

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
$\label{eq:maximum Instantaneous Forward Voltage (Note 4)} \begin{tabular}{l} (I_F = 1.0 \ A, \ T_J = 25^\circ C) \\ (I_F = 2.0 \ A, \ T_J = 25^\circ C) \\ (I_F = 1.0 \ A, \ T_J = 125^\circ C) \\ (I_F = 2.0 \ A, \ T_J = 125^\circ C) \\ \end{tabular}$	V _F	0.76 0.84 0.61 0.68	V
Maximum Instantaneous Reverse Current (Note 4) (Rated dc Voltage, $T_J = 25^{\circ}\text{C}$) (Rated dc Voltage, $T_J = 125^{\circ}\text{C}$)	I _R	20 1.0	μA mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Mounted with 700 mm² copper pad size (Approximately 1 in²) 1 oz FR4 Board.

- 3. Mounted with pad size approximately 20 mm² copper, 1 oz FR4 Board.
- 4. Pulse Test: Pulse Width \leq 380 μ s, Duty Cycle \leq 2.0%.

^{1.} The heat generated must be less than the thermal conductivity from Junction–to–Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

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TYPICAL CHARACTERISTICS

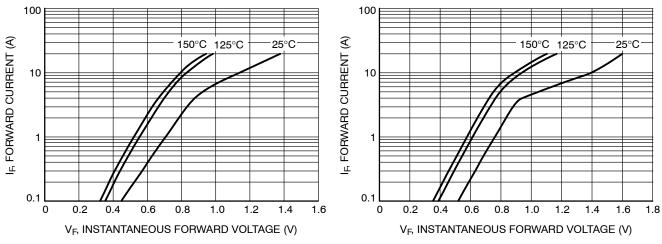


Figure 1. Typical Forward Voltage

Figure 2. Maximum Forward Voltage

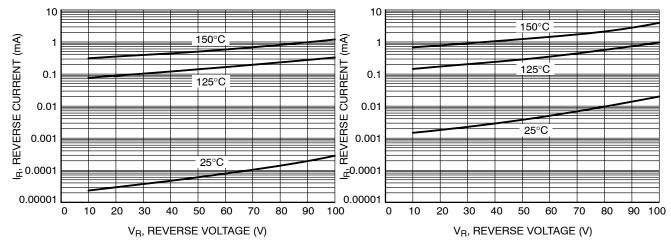


Figure 3. Typical Reverse Current

Figure 4. Maximum Reverse Current

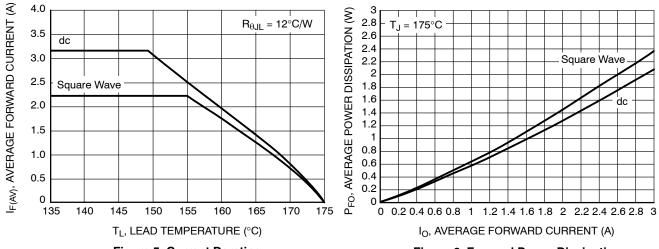


Figure 5. Current Derating

Figure 6. Forward Power Dissipation

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TYPICAL CHARACTERISTICS

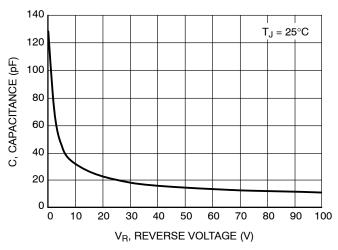


Figure 7. Capacitance

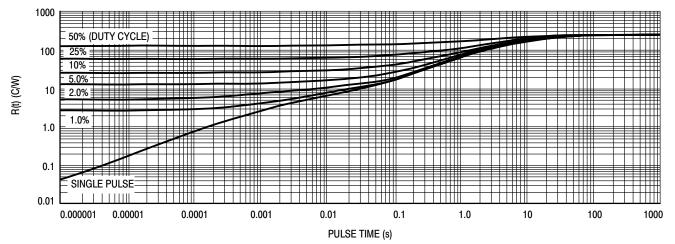


Figure 8. Thermal Response, Junction-to-Ambient (20 mm² pad)

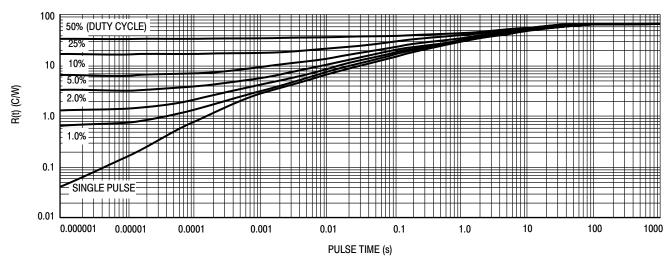
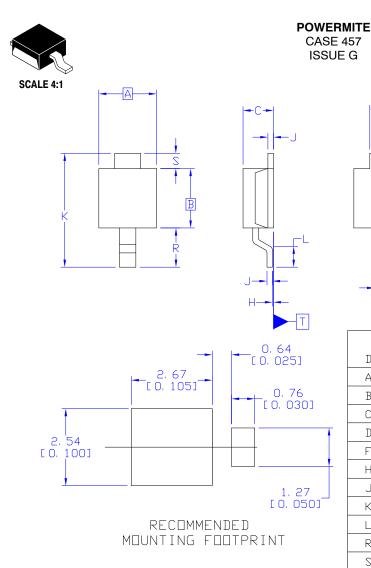


Figure 9. Thermal Response, Junction-to-Ambient (1 in² pad)

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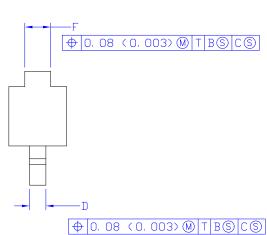


DATE 12 JAN 2022



GENERIC

MARKING DIAGRAMS*



	MILLIMETERS		INCHES	
DIM	MIN.	MAX.	MIN.	MAX.
А	1. 75	2, 05	0, 069	0. 081
В	1. 75	2. 18	0, 069	0, 086
С	0. 85	1. 15	0. 033	0. 045
D	0. 40	0. 69	0. 016	0. 027
F	0. 70	1. 00	0. 028	0. 039
Н	-0. 05	0. 10	-0. 002	0. 004
J	0.10	0, 25	0. 004	0.010
К	3, 60	3, 90	0.142	0. 154
L	0, 50	0, 80	0, 020	0. 031
R	1. 20	1, 50	0. 047	0, 059
S	0.50 REF		REF 0.019 REF	

NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS

STYLE 2:

CATHODE

2. ANODE

3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30mm FROM THE TERMINAL TIP.

PIN 1. ANODE OR CATHODE

2. CATHODE OR ANODE (BI-DIRECTIONAL)

IT NI IN	ARER:	00ASB140E2	C	Electronic versions
	STYLE	3 .	= Pb-Free Pa	ckage
_		<u> </u>	= Date Code	
\neg		XX	X = Specific Dev	ice Code
1	M XXX■	2		*
\Box	M			
1		STYLE 2		2.
]	STYLE 1: PIN 1. (

XXX.

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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STYLE

STYLE 3:

PIN 1. ANODE 2. CATHODE

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